Pb Free Plating Product

HER2002FCR-HER2012FCR

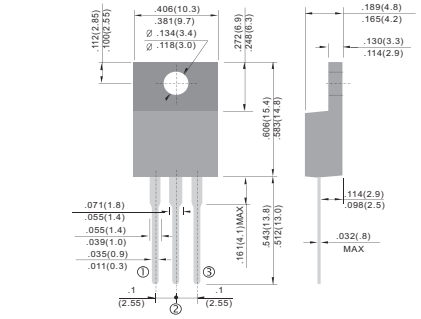
20.0 Ampere Insulated Dual Doubler Polarity High Efficiency Rectifiers

Features
※ ThinkiSemi latest&matured process FRD/FRED
※ Low forward voltage drop
※ High current capability
※ Low reverse leakage current
※ High surge current capability

Application
※ Automotive Inverters and Solar Inverters
※ Car Audio Amplifiers and Sound Device Systems
※ Plating Power Supply,Motor Control,UPS and SMPS etc.

Mechanical Data
※Case:Isolated fully plastic ITO-220AB/TO-220F-3L package
※ Epoxy: UL 94V-0 rate flame retardant
※ Terminals: Solderable per MIL-STD-202 method 208
※ Polarity: As marked on diode body
※ Mounting position: Any
※ Weight: 2.0 gram approximately

ITO-220AB/TO-220F-3L Unit:inch(mm)



MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Rating at 25℃ ambient temperature unless otherwise specified.
Single phase,half wave,60Hz,resistive or inductive load.
For capacitive load, derate current by 20%.

PARAMETER	SYMBOL	HER2002FCR	HER2003FCR HER2004FCR	HER2006FCR	HER2008FCR	HER2010FCR	HER2012FCR	UNIT
Maximum Recurrent Peak Reverse Voltage	VRRM	200	400	600	800	1000	1200	V
Maximum RMS Voltage	VRMS	140	280	420	560	700	840	V
Maximum DC Blocking Voltage	VDC	200	400	600	800	1000	1200	V
Maximum Average Forward Rectified Current TC=125℃ (Total Device 2x10.0A=20.0A)	IF(AV)	20.0						A
Peak Forward Surge Current, 8.3ms single Half sine-wave superimposed on rated load (JEDEC method)(Per Diode/Per Leg)	IFSM	200						A
Maximum Instantaneous Forward Voltage @10.0A(Per Diode/Per Leg)	VF (Typical)	0.85-1.00	1.00-1.30	1.30-1.70	1.30-1.70			V
Maximum DC Reverse Current @TJ=25℃ At Rated DC Blocking Voltage @TJ=125℃	IR	1.0 100						μA μA
Maximum Reverse Recovery Time (Note1)	Trr	35-50			50-75			nS
Typical Junction Capacitance (Note 2)	CJ	100						pF
Typical Thermal Resistance (Note 3)	RθJC	3.0						℃/W
Operating Junction and Storage Temperature Range	TJ,TSTG	-55 to +175						℃

Note:(1)Reverse recovery test conditions IF = 0.5A, IR = 1.0A, Irr = 0.25A.

Note:(2)Measured at 1.0 MHz and applied reverse voltage of 4.0 Volts DC.

Note:(3)Thermal Resistance junction to case.

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FIG.1 - FORWARD CURRENT DERATING CURVE

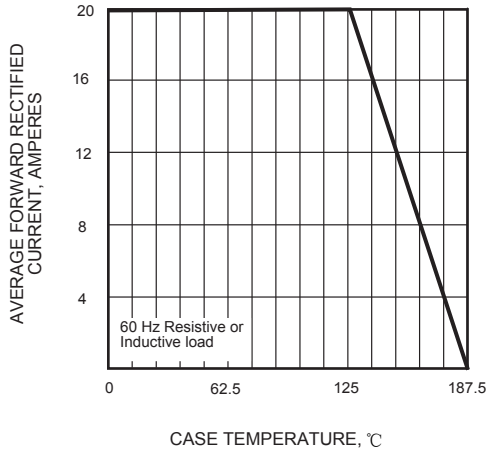


FIG.2 - MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

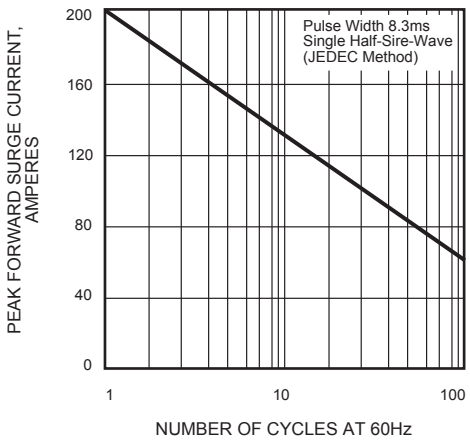


FIG.3 - TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

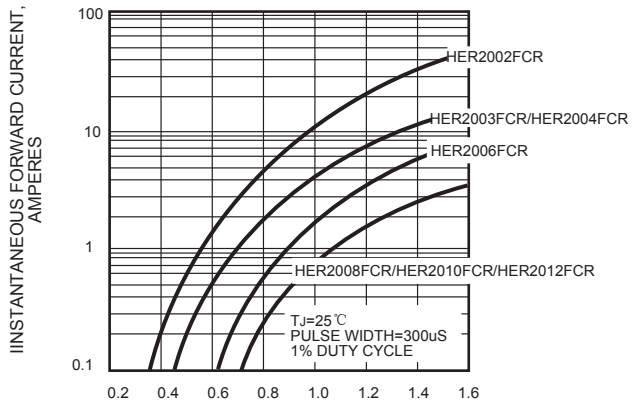


FIG.4 - TYPICAL REVERSE CHARACTERISTICS

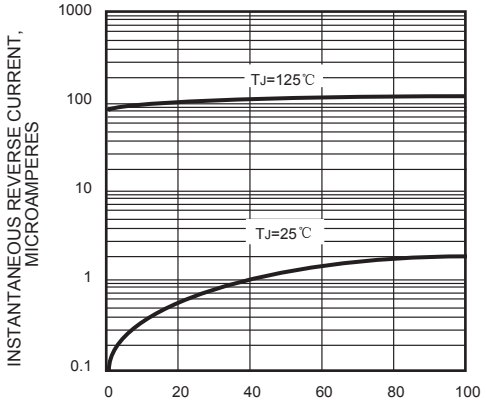
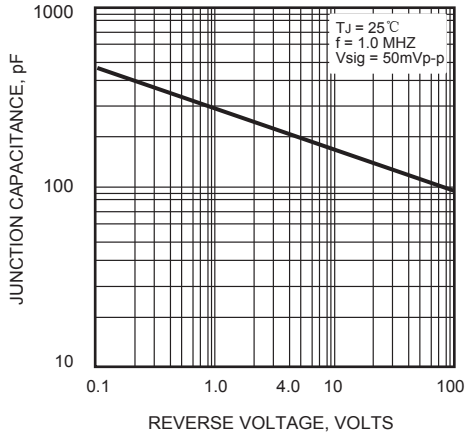


FIG.5 - TYPICAL JUNCTION CAPACITANCE



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